1N5819-1 1N5819UR-1

TECHNICAL DATA DATA SHEET 193, REV. B JAN JANTX JANTXV

# HERMETIC AXIAL LEAD / MELF SCHOTTKY BARRIER DIODE

DESCRIPTION: A 45 VOLT, 1.0 AMP, AXIAL LEAD/SURFACE MOUNT SCHOTTKY BARRIER DIODE.

#### **MAXIMUM RATINGS**

All ratings are at  $T_A = 25^{\circ}$ C unless otherwise specified.

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RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV)	1	-	-	45	Vdc
Average DC Output Current (I <sub>o</sub> )	2	-	-	1.0	Amps
Peak Single Cycle Surge Current (I <sub>fsm</sub> )	t <sub>p</sub> = 8.3 ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	25	Amps(pk)
Thermal Resistance ( <sub>0JL</sub> )	Junction to Lead d = 0.375"	-	-	70	°C/W
Thermal Resistance ( $\theta_{\text{JEC}}$ )	Junction to Endcap	-	-	40	°C/W
Junction Temperature (T <sub>J</sub> )	-	-55	-	+125	°C
Operating Temperature (T <sub>op)</sub>	-	-55	-	+125	°C
Storage Temp. (T <sub>stg</sub> )	-	-55	-	+150	°C

### **ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC	CONDITIONS	MIN	TYP	MAX	UNIT
Maximum Forward Voltage (V <sub>f</sub> )	I <sub>F</sub> = 1.0A (300 μsec pulse, duty cycle < 2%)	-	-	0.49	Volts
Maximum Instantaneous Reverse Current At Rated (PIV)	T <sub>A</sub> = 25° C T <sub>A</sub> = 100° C	-	-	0.05 4.0	μAmps mAmps
Junction Capacitance (C <sub>J</sub> )	$\begin{aligned} &V_R = 5 \text{ Vdc} \\ &0.01 \leq f \leq 1 \text{MHz} \\ &V_{sig} = 15 \text{ mV p-p} \end{aligned}$	-	-	70	pF

**Notes:** - All ratings are at TA = 25°C unless otherwise specified.

<sup>-</sup> Maximum storage temperature range: -55°C to +150°C.

<sup>-</sup> Maximum operating temperature range: -55°C to +125°C (1N5819-1, 1N5819UR-1).

 $<sup>\</sup>odot$  Derate linearly at 4.5 V/°C above T<sub>L</sub> or T<sub>EC</sub> = +100°C (1N5819-1), where T<sub>EC</sub> is at L = .375 inch.

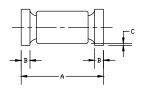
② Derate linearly at 14 mA/°C above  $T_L$  or  $T_{EC}$  = +55°C (1N5819-1), where  $T_{EC}$  is at L = .375 inch.

# **DATA SHEET 193, REV. A**

**AXIAL** 



# **MELF**





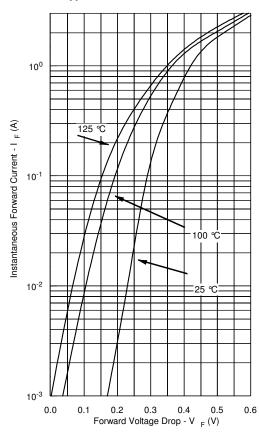
SCHOTTKY BARRIER 1N5819-1

PACKAGE	DIMENSIONS - INCHES (MILLIMETERS)				
STYLE	φВ	φD	G	L	
	.028/.034	.08/.107	.160/.205	1.00/1.30	
DO-41	0.71/0.86	2.03/2.72	4.06/5.21	25.4/33.02	

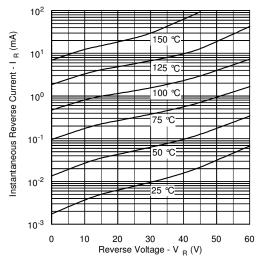
SCHOTTKY BARRIER 1N5819UR-1

PACKAGE	DIMENSIONS - INCHES (MILLIMETERS)				
STYLE	Α	В	С	D	
	.189/.205	.016/.022	0.001 Min	.094/.105	
DO-213AB	4.80/5.21	0.41/0.56	0.03 Min	2.39/2.67	

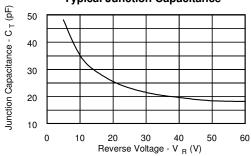
## **Typical Forward Characteristics**



# **Typical Reverse Characteristics**



## **Typical Junction Capacitance**



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#### **TECHNICAL DATA**

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